

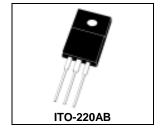
Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 150¢J Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

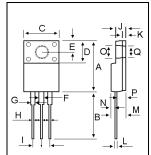
SCHOTTKY BARRIER RECTIFIERS

20 AMPERES 150 VOLTS

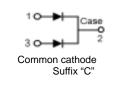


MAXIMUM RATINGS

Characteristic	Symbol	SRF20150C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	150	٧
RMS Reverse Voltage	V _{R(RMS)}	105	٧
Average Rectifier Forward Current Total Device (Rated V _R),T _C =100¢J	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	150	А
Operating and Storage Junction Temperature Range	T _J , T _{STG}	-65 to +150	¢I



DIM	MILLIMETERS			
ווועו	MIN	MAX		
Α	15.05	15.15		
В	13.35	13.45		
С	10.00	10.10		
D	6.55	6.65		
Ε	2.65	2.75		
F	1.55	1.65		
G	1.15	1.25		
Н	0.55	0.65		
1	2.50	2.60		
J	3.00	3.20		
K	1.10	1.20		
L	0.55	0.65		
M	4.40	4.60		
N	1.15	1.25		
Р	2.65	2.75		
0	3.35	3.45		
Q	3.15	3.25		



ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	SRF20150C	Unit
$\begin{aligned} &\text{Maximum Instantaneous Forward Voltage} \\ &\text{(I}_F = &10 \text{ Amp T}_C = 25 \text{ (a)} \text{)} \\ &\text{(I}_F = &10 \text{ Amp T}_C = 125 \text{ (a)} \text{)} \end{aligned}$	V _F	0.95 0.85	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25 \omega$) (Rated DC Voltage, $T_C = 125 \omega$)	I _R	0.5 20	mA

